

METHOD OF APPLYING A BOTTOM SURFACE PROTECTIVE
COATING TO A WAFER, AND WAFER DICING METHOD

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Background of the Invention:

Field of the Invention:

10 The invention lies in the semiconductor processing technology
field. More specifically, the present invention relates to a
method for applying a protective coating to a bottom surface
of a semiconductor wafer, especially with regard to the
subsequent dicing of the wafer into separate semiconductor
chips. After the fabrication of integrated circuits on the
wafer, the wafer is diced by sawing or etching along parallel
lines. During the sawing process, the edges of the chips are
subject to various damage sources, such as splitting or
chipping. Accordingly, a protection of the semiconductor dies
is required.

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20 U.S. Patent No. 6,023,094 to Kao et al. describes a
semiconductor wafer having a bottom surface protective
coating. That protective film on the bottom surface is
intended to aid in preventing chipping during the wafer dicing
process, and is formed by any process suitable for applying a
25 thick film. In one embodiment, a screen printing process is
utilized. There, a screen is placed over the bottom surface

and the material to be deposited is dragged by means of a squeegee. By way of another example, a spinning type process may be used, wherein a thick film is spread across the bottom surface of the wafer.

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A holding structure is utilized to protect the wafer during the application of the thick film. The wafer is mounted onto a mounting tape, the thick protective film facing the mounting tape. Any suitable cutting device is utilized to separate the dies from one another. Additionally, the protective film is intended to improve adhesion to the mounting tape, making it possible to use mounting tapes with inferior adhesion strength.

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Summary of the Invention:

It is accordingly an object of the invention to provide an improved method for applying a protective coating to a bottom surface of a semiconductor wafer, which overcomes the above-mentioned disadvantages of the heretofore-known devices and methods of this general type and which provides sufficient protection against damage and allows for easy processing.

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With the foregoing and other objects in view there is provided, in accordance with the invention, a method of applying a protective coating to a bottom surface of a wafer, which comprises the steps of:

forming trenches in a top surface of the wafer;

applying a top side dicing tape to the top surface;

grinding the wafer at a bottom surface opposite the top surface and thereby laying open the trenches;

5 applying a protective material on the bottom surface and filling the trenches; and

hardening the protective material to form a protection layer.

The forgoing method is advantageously applied to the dicing of a semiconductor wafer. In that case, the following additional steps are performed:

fixing the protection layer to a mounting tape for fastening the wafer onto a dicing frame;

removing the top side dicing tape;

15 dicing the wafer into dies; and

picking the dies off the mounting tape.

With the above and other objects in view there is also provided, in accordance with another embodiment of the

invention, a method of applying a protective coating to a bottom surface of a wafer, which comprises the steps of:

forming trenches in a top surface of the wafer;

applying a top side dicing tape to the top surface;

5 grinding the wafer at a bottom surface opposite the top surface and thereby laying open the trenches;

applying a glue layer onto a mounting tape; and

mounting the wafer on the mounting tape and causing the glue to fill the trenches.

10 Again, this method is expediently utilized in a method of dicing a semiconductor wafer, which comprises:

applying a protective coating to a bottom surface of the wafer as above, and further

15 removing the top side dicing tape;

dicing the wafer into dies; and

picking the dies off the mounting tape.

Finally, there is also provided, in accordance with the

20 invention, a method of applying a protective coating to a

bottom surface of a wafer, which comprises the following steps:

applying a protective foil onto a mounting tape; and

mounting a bottom surface of the wafer onto the mounting tape

5 with the protective foil facing the wafer.

The method is advantageously utilized for dicing a semiconductor wafer, whereby the following steps are performed:

10 applying a protective coating to a bottom surface of the wafer as outlined above; and further
dicing the wafer including the protective foil into dies; and
picking the dies with the protective foil off the mounting tape.

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In accordance with a concomitant feature of the invention, the mounting tape is a UV-foil; and the step of picking off the dies includes applying UV-radiation to separate the UV-foil from the protective foil.

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Once more in summary, to achieve the foregoing and other objects, the present invention provides a new backside treatment of the wafer. Trenches are cut into the top surface

of the wafer by sawing or etching, and after grinding the wafer from the bottom side, a protective material is applied as a surface layer to the bottom surface while filling the trenches with this material. The material is hardened in order

5 to accomplish the subsequent sawing process. In another embodiment of the present method, a double foil layer is applied to the rear side of the wafer including a mounting tape and a protective layer facing the wafer rear side.

10 Other features which are considered as characteristic for the invention are set forth in the appended claims.

15 Although the invention is illustrated and described herein as embodied in a method for applying a protective coating to a bottom wafer surface, it is nevertheless not intended to be limited to the details shown, since various modifications and structural changes may be made therein without departing from the spirit of the invention and within the scope and range of equivalents of the claims.

20 The construction and method of operation of the invention, however, together with additional objects and advantages thereof will be best understood from the following description of specific embodiments when read in connection with the accompanying drawings.

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Brief Description of the Drawings:

Figs. 1 to 3 are diagrammatic sectional views of a wafer after different steps of the manufacturing process; and

5 Fig. 4 is a section similar to Fig. 3 for an alternative fabrication method.

Description of the Preferred Embodiments:

10 Referring now to the figures of the drawing in detail and first, particularly, to Fig. 1 thereof, in a first embodiment of the invention, trenches, especially provided as dicing channels, are cut into the top surface of the wafer according to the lines of separation between the chips to be diced. The trenches can be sawn or etched, for example. The chips are not
15 yet separated, as the trenches are cut to a certain depth only. Fig. 1 shows a section of a wafer 1 with trenches 2 cut into the top surface to a certain depth, not separating the dies. A top side dicing tape 3 covering the integrated circuits fabricated on the wafer is applied to the top surface
20 in the direction of the arrows.

Following this kind of a dicing-before-grinding methodology, the thickness of the wafer is then reduced from the bottom side by a usual grinding process. In the course of this
25 grinding process, the trenches are laid bare and are opened on the bottom surface. Fig. 2 shows the remaining wafer 4 upside

down, after a protective material 5 has been applied to the bottom surface opposite to the top side, which still carries the top side dicing tape 3. The protective material 5 is a low viscosity material, which will form a thin, planar protection layer across the bottom surface of the wafer, at the same time filling all of the trenches or dicing channels. To this end, an appropriate material, for example a varnish or resist, can be poured onto the bottom surface and distributed with slow spin. Alternatively, an appropriate material can be applied by using a screen printer system in a process that is equivalent to the process described in the above-mentioned U.S. Patent No. 6,023,094.

Instead of applying a continuous surface layer only, the trenches are filled with the protective material as well. Dicing channels are typically only 50 micrometers wide. Therefore a sufficiently low viscosity is a requirement for an adequate choice of the protective material. Further to that, the protective material is chosen so that it can be hardened or will lose its low viscosity or fluidity in the course of the fabrication process; thus it will form a protection layer and can be sawn in a later process step.

Fig. 3 shows a section of the remaining wafer 4, now made up of the dies 4 that are held together by the protective material 5, after the wafer has been mounted on a mounting

tape 6 and fastened to a dicing frame 7. The top side dicing tape 3 is removed so that the protective material 5 in the dicing channels between the dies 4 can be cut. Preferably, a saw with a thinner blade than the instrument possibly used to cut the trenches is used to separate the dies 4. Thereafter the dies can be picked off the mounting tape 6.

10 An especially preferred variant embodiment comprises a thick glue layer applied to the mounting tape before mounting the wafer comprising the dies 4 that are fastened by the top side dicing tape after the grinding process; this glue layer substitutes the separate application of the protective material 5 by a screen printer system or a resist spinning equipment. In this embodiment, the bottom surface of the wafer - that is the surface opposite to the surface with the top side dicing tape 3 - is brought into contact with the glue layer on the mounting tape. The glue layer is intended to fill the trenches between the dies 4 and takes essentially the same space as the protective material 5 shown in Fig. 3. The glue layer can be hardened using ultraviolet light, for instance; instead, it is possible to apply a sort of glue that will become harder after a short intermediate time interval. The glue has the property to adhere to the dies 4 while relatively easily detaching from the mounting tape 6. So the hardened glue layer remains on the backsides of the separated dies.

An alternative procedure of applying a protective layer on the
backsides of the dies comprises the application of a double
foil layer as a mounting tape. To this end, a protective
5 second foil is laminated to the mounting tape that is intended
to be used for mounting the wafer to the dicing frame. The
wafer is mounted to the mounting tape, the protective foil of
the double foil layer facing the wafer. Thus the bottom
surface of the wafer is put into contact with the protective
10 foil. In the process of dicing the protective foil is cut
together with the dies of the wafer.

The separated chips are picked off the mounting tape with the
appertaining part of the protective foil adhering to the
15 bottom surface of each separate die. The adhesive strength
between the mounting tape proper and the protective foil is
adjusted inferior to the adhesive strength between the
protective foil and the semiconductor material of the wafer.
This can be accomplished by adjusting the adhesive forces
20 acting between the layers, or by means of an ultraviolet foil
used as mounting tape. Such an ultraviolet foil is detached
from the material to which it is applied by use of ultraviolet
radiation. The UV radiation destroys the adhesive bonds
between the foil and the substrate. Also a thermally
25 conductive foil may be used as protective foil, especially if

